

## 1650 nm laser diode - DFB

Model 4 : >100 mW / singlemode fiber / 14 pin Butterfly package

Reference: 1650LD-4-0-0

Technology : DFB\*

SPECIFICATIONS		Min		Maximum
Output Power (CW mode)	mW	100		
Output Power (Pulse mode)	mW		>180	
Center Wavelength (CW)	nm	1645	1650	1655
Spectral Width (FWHM)	kHz		160	200
Threshold Current	mA		20	30
Operating Current	mA		700	800
Operation Voltage	V		1.8	2.0
Wavelength shift w Temperature	nm/°C		0.08	
Wavelength shift w Current	nm/mA		0.003	
Side mode suppression ratio	dB	35	50	
Internal Photodiode Responsivity	mA/W	5		
Internal Photodiode Dark Current	nA			500
TEC current (-5/60°C)	A			1
TEC Voltage (-5/60°C)	V			1.5
Internal thermistor (25°C)	kOhm	9.5	10	10.5
Fiber type	PM1550 or equivalent			
Coating diameter	µm		900	
Fiber bend radius	mm	30		
Storage case temperature	°C	-40		70
Case operating temperature	°C	-20		60
Lead soldering temperature	°C		260	300
Laser diode reverse voltage	V			15
Pigtail termination	FC/APC connector			
Polarization state (PM version)	Aligned to the slow axis			

Form factor & Laser diode pinning (standard 14-pin Butterfly Type-1) :

